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DATE MAILED: 12/03/2003

APPLICATION NO.	FILING DATE		FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/926,713	0	3/05/2002	Yasuji Hiramatsu	216723US2PCT 3517		
22850	7590	12/03/2003		EXAMINER		
OBLON, SI		MCCLELLAND, M	PAIK, SANG YEOP			
ALEXANDRIA, VA 22314				ART UNIT	PAPER NUMBER	
•	,			3742		

Please find below and/or attached an Office communication concerning this application or proceeding.

•					[./			
		Application	on No.	Applicant(s)				
		09/926,7	13	HIRAMATSU, YA	SUJI			
	Office Action Summary	Examiner		Art Unit				
	•	Sang Y Pa		3742				
	The MAILING DATE of this communic				ldress			
Period fo								
THE - Exte after - If the - If NO - Failt - Any	ORTENED STATUTORY PERIOD FO MAILING DATE OF THIS COMMUNIC nsions of time may be available under the provisions of SIX (6) MONTHS from the mailing date of this common of period for reply specified above is less than thirty (30) period for reply is specified above, the maximum stature to reply within the set or extended period for reply we reply received by the Office later than three months after the patent term adjustment. See 37 CFR 1.704(b).	CATION. f 37 CFR 1.136(a). In no evenication. days, a reply within the statutory period will apply and will, by statute, cause the app	ent, however, may a reply be tim utory minimum of thirty (30) days Il expire SIX (6) MONTHS from i ication to become ABANDONED	ely filed will be considered time the mailing date of this c (35 U.S.C. § 133).	ly. ommunication.			
1)⊠	Responsive to communication(s) filed	l on <u>17 September 2</u>	<u>2003</u> .					
· _	,)⊠ This action is no						
3)□	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Disposit	ion of Claims							
4)⊠	Claim(s) 1-30 is/are pending in the ap	plication.						
•	4a) Of the above claim(s) is/are		nsideration.					
5)□	Claim(s) is/are allowed.							
6)⊠	Claim(s) <u>1-30</u> is/are rejected.							
7)	Claim(s) is/are objected to.							
8)	Claim(s) are subject to restricti	ion and/or election r	equirement.					
Applicat	ion Papers							
, , , , , , , , , , , , , , , , , , , ,	The specification is objected to by the							
10)	The drawing(s) filed on is/are:	a) accepted or b)	objected to by the E	Examiner.				
	Applicant may not request that any object	• • •	•	. ,				
44)	Replacement drawing sheet(s) including to	•	-, · ·		, -			
•	The oath or declaration is objected to	by the Examiner. No	nte trie attached Office	Action of form P	10-152.			
_	under 35 U.S.C. §§ 119 and 120 Acknowledgment is made of a claim f		dan 05 11 0 0 0 440/a) (4) (6)				
* (13)	☐ All b)☐ Some * c)☐ None of: 1.☐ Certified copies of the priority d 2.☐ Certified copies of the priority d 3.☐ Copies of the certified copies of application from the Internation See the attached detailed Office action Acknowledgment is made of a claim for ince a specific reference was included 7 CFR 1.78. a) ☐ The translation of the foreign lang Acknowledgment is made of a claim for acknowledgment is ma	locuments have bee locuments have bee f the priority docume all Bureau (PCT Rulfor a list of the certion domestic priority up in the first sentence guage provisional approduced to the priority up to the	n received. n received in Application received in Application that have been received at 17.2(a)). fied copies not received and a 19.6 field that is u.S.C. § 119(e) of the specification or plication has been received at 35 U.S.C. §§ 120	on No d in this National d. t) (to a provisional in an Application eived. and/or 121 since	al application) Data Sheet. a specific			
r	eference was included in the first sente	ence of the specifica	tion or in an Applicatio	n Data Sheet. 37	CFR 1.78.			
Attachmen	t(s)							
2) Notic	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PT mation Disclosure Statement(s) (PTO-1449) Pap		4) Interview Summary 5) Notice of Informal P 6) Other:					

U.S. Patent and Trademark Office PTOL-326 (Rev. 11-03)

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DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.

The changes made to 35 U.S.C. 102(e) by the American Inventors Protection Act of 1999 (AIPA) and the Intellectual Property and High Technology Technical Amendments Act of 2002 do not apply when the reference is a U.S. patent resulting directly or indirectly from an international application filed before November 29, 2000. Therefore, the prior art date of the reference is determined under 35 U.S.C. 102(e) prior to the amendment by the AIPA (pre-AIPA 35 U.S.C. 102(e)).

2. Claims 1-5, 8-14 and 16-19 are rejected under 35 U.S.C. 102(b) as being anticipated by Holmes (US 4,217,570).

Holmes anticipates the structure claimed including a ceramic substrate made of silicon nitride with a thickness of 10 mm or less, an insulating layer made of silicon oxide which is disclosed by the applicant to have the resistive volume higher than the silicon nitride where the volume resistance of the insulating layer is not less than 10 times larger than the volume resistivity of the silicon nitride ceramic substrate, a resistance heating element formed on the insulating layer and the thickness of the insulating layer being at minimum average of .1 um, the resistance heating element further having at least one of the claimed noble metal such as nickel

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and a conductive ceramic such as oxides of aluminum, silicon, tantalum, titanium, and zirconium.

Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 1-3, 5, 8, 12-16, 18 and 20-22 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ishii (US 5,851,298) in view of Nobori et al (US 5,616,024) or Kawanabe et al (US 6,133,557).

Ishii shows a ceramic heater having a ceramic substrate made of nitride and the insulating layer made of oxide ceramic such as alumina having the volume resistivity not less than 10 times higher than that of the ceramic substrate and a resistance heating element formed in the insulating layer. However, Ishii does not disclose that the heating element is formed on the insulating layer.

Nobori et al shows a ceramic heater having a heating element formed on a ceramic layer which is then molded with another ceramic layer substrate. Kawanabe et al also shows a ceramic heater having a heating element formed on a ceramic layer which is laminated with another ceramic layer to form a ceramic heater. In view of Nobori et al or Kawanabe et al, it would have been obvious to one of ordinary skill in the art to provide a resistance heating element on an insulating layer as an alternative heating arrangement to securely place a heating element on a ceramic heater.

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Kawanabe et al shows the resistance heating element made of tungsten, molybdenum and aluminum nitride and that the diameter of the ceramic heater is 8 inches which is equivalent to about 203 mm (see column 13, lines 31-55). It would have been obvious to one of ordinary skill in the art to adapt Ishii with the diameter with the claimed range to accommodate the wafer that is being heating on the surface of the ceramic heater and, although, it is not shown that the diameter of the ceramic substrate can be more than 300 mm, it would have been further obvious to one of ordinary skill in the art to adapt the ceramic substrate having the diameter more than 300 mm to accommodate various sizes of wafer that would have heated by the ceramic substrate.

Nobori et al furher shows that the heating element made of tungsten or molybdenum having a plurality of circuits and a bottomed hole to provide a temperature-measuring element therein. In view of Nobori et al, it would have been obvious to one of ordinary skill in the art to adapt Ishii with a plurality of circuits to have a plural heating element that can be independently controlled to provide the desired heating across the heating surface and further adapt with a temperature sensor to measure the heating temperature to maintain the desired heating.

5. Claim 17 is rejected under 35 U.S.C. 103(a) as being unpatentable over Ishii in view of Nobori et al or Kawanabe et al as applied to claims 1-3, 5, 8, 12-16, 18 and 20-22 above, and further in view of Fukazawa et al (US 4,449,039).

Ishii in view of Nobori et al or Kawanabe et al discloses all the structure claimed except the heating element is comprised of metal oxides.

Fukazawa et al shows a ceramic heater with a resistance heating element made of a metal oxide such as alumina. In view of Fukzawa et al, it would have been obvious to one of ordinary skill in the art to adapt Ishii, as modified by Nobori et al or Kawanabe et al, with the heating

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element having a metal oxide to improve the oxidation and thermal resistance in high operating temperatures.

6. Claims 6, 7, 24 and 26-29 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yoshida et al (US 6,080,970) or Kawanabe et al (US 6,133,557) in view of Yusio et al (US 6,423,400).

Kawanabe et al or Yoshida et al shows a ceramic heater having a ceramic substrate with a resistance heating element formed on a surface of the ceramic substrate (see column 7, lines 23-35; and, column 5, lines 52-64, respectively). However, the claimed warped ceramic substrate is not shown.

Yusio et al shows a wafer supporting ceramic substrate susceptor having a warped ceramic substrate in one direction. Yusio et al also shows that the warped amount can be in the range of 10 microns or more (see column 16, line 12). In view of Yusio et al, it would have been obvious to one of ordinary skill in the art to adapt Kawanabe et al or Yoshida et al with the warped substrate having the claimed range to provide a close thermal contact between the wafer and the wafer heating/supporting ceramic heater so that a high thermal conductivity can be made.

Kawanabe et al shows the resistance heating element made of tungsten, molybdenum and aluminum nitride. Kawanabe et al further shows that the ceramic heater is made of laminating green sheets having the thickness of about .5 mm and that one of the ceramic substrate is shown to have the thickness of 10 mm and the diameter of 8 inches which is equivalent to about 203 mm (see column 13, lines 31-55). Although, it is not shown that the diameter of the ceramic substrate can be more than 300 mm, it would have been obvious to one of ordinary skill in the art

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to adapt the ceramic substrate having the diameter more than 300 mm to accommodate various sizes of wafer that would have heated by the ceramic substrate.

Yoshida et al further shows the resistance heating element made of tungsten, molybdenum, and carbides or nitrides of metals.

7. Claims 23 and 30 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yoshida et al or Kawanabe et al in view of Yusio et al as applied to claims 6, 7, 24 and 26-29 above, and further in view of Nobori et al (US 5,616,024).

Yoshida et al or Kawanabe et al in view of Yusio et al discloses all the structure claimed except the heating element having a plurality of circuits.

Nobori et al shows a ceramic heater having a heating element having a plurality of circuits, and Nobori et al further shows a bottomed hole to provide a temperature-measuring element therein. In view of Nobori et al, it would have been obvious to one of ordinary skill in the art to adapt Yoshida et al or Kawanabe et al, as modified by Yusio et al, with a plurality of circuits to have a plural heating element that can be independently controlled to provide the desired heating across the heating surface and further adapt with a temperature sensor to measure the heating temperature to maintain the desired heating.

8. Claim 25 is rejected under 35 U.S.C. 103(a) as being unpatentable over Yoshida et al or Kawanabe et al in view of Yusio et al as applied to claims 6, 7, 24 and 26-29 above, and further in view of Fukazawa et al (US 4,449,039).

Yoshida et al or Kawanabe et al in view of Yusio et al discloses all the structure claimed except the heating element is comprised of metal oxides.

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Fukazawa et al shows a ceramic heater with a resistance heating element made of a metal

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oxide such as alumina. In view of Fukzawa et al, it would have been obvious to one of ordinary

skill in the art to adapt Yoshida et al or Kawanabe et al, as modified by Yusio et al, with the

heating element having a metal oxide to improve the oxidation and thermal resistance in high

operating temperatures.

Response to Arguments

9. Applicant's arguments with respect to claims 1-30 have been considered but are moot in

view of the new ground(s) of rejection.

10. Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Sang Y Paik whose telephone number is 703-308-1147. The

examiner can normally be reached on M-F (8:00-5:30) First Friday Off.

The fax phone number for the organization where this application or proceeding is

assigned is 703-872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding

should be directed to the receptionist whose telephone number is 703-308-0861.

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Sang Y Paik Primary Examiner Art Unit 3742

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